



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Tatsuya Usami

Serial No.: 09/851,313

Group Art Unit: 2823

Filed: May 9, 2001

Examiner: Maldonado, J.

For: SEMICONDUCTOR DEVICE AND SEMICONDUCTOR WAFER (Amended)

Honorable Assistant Commissioner of Patents
Washington, D.C. 20231

#10/B
8-30-02
RECEIVED
Mallish
AUG 26 2002
TECHNOLOGY CENTER 2800

AMENDMENT UNDER 37 C.F.R. §1.111

Sir:

In response to the Office Action dated **May 8, 2002**, please amend the above-identified application as follows:

THE TITLE:

Please replace the original title with the following title:

SEMICONDUCTOR DEVICE AND SEMICONDUCTOR WAFER

IN THE CLAIMS:

Please cancel claims 9-30 without prejudice or disclaimer.

Please amend the following claims:

1. (Amended) A semiconductor device comprising:

a multi-layered insulation film formed on a semiconductor substrate, said multi-layered insulation film comprising:

a first insulation layer comprising an organic material having a dielectric constant which is lower than a silicon oxide dielectric constant;

a second insulation layer comprising a polysiloxane compound having an Si-H group

B
P
C